

FEATURES

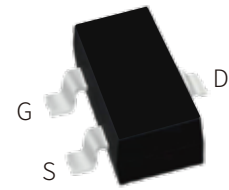
Ultra low on-resistance: $V_{DS}=30V, R_{DS(ON)} \leq 47m\Omega$

@ $V_{GS}=10V, I_D=3.16A$

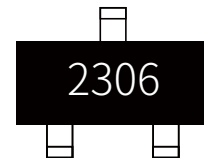
For Low power DC to DC converter application

For Load switch application

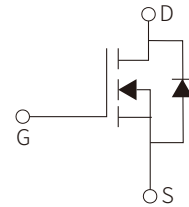
Surface Mount device



SOT-23



Marking



Schematic Symbol

APPLICATION

Case: SOT-23

Case Material: Molded Plastic. UL flammability

Classification Rating: 94V-0

APPROVALS

RoHS Compliance with 2011/65/EU

HF Compliance with IEC61249-2-21:2003

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Continuous drain current	I_D	3.16	A
Pulsed drain current (Note 1)	I_{DM}	20	A
Gate-Source Voltage	V_{GS}	± 20	V
Power dissipation	P_D	0.75	W
Thermal resistance from Junction to ambient	$R_{\theta JA}$	100	$^\circ C/W$
Junction temperature	T_J	150	$^\circ C$
Storage temperature	T_{STG}	-55 to 150	$^\circ C$

ELECTRICAL CHARACTERISTICS($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=30V, V_{GS}=0V$			0.5	μA
Gate-Body Leakage	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage (Note1)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1		3.0	V
Static Drain-Source On-Resistance(Note1)	$R_{DS(on)}$	$V_{GS}=10V, I_D=3.5A$		38	47	m Ω
		$V_{GS}=4.5V, I_D=2.8A$		52	65	
Forward Transconductance(Note1)	g_{FS}	$V_{DS}=4.5V, I_D=2.5A$		7.0		S
Input Capacitance	C_{iss}	$V_{DS}=15V, V_{GS}=0V, f=1.0\text{MHz}$		305		pF
Output Capacitance	C_{oss}			65		
Reverse Transfer Capacitance	C_{rss}			29		
Turn-On Delay Time	$t_{d(on)}$	$V_{GEN}=10V, R_G=6\Omega$ $V_{DD}=15V, I_D=1A$ $R_L=15\Omega$		7	11	ns
Turn-On Rise Time	t_r			12	18	
Turn-Off Delay Time	$t_{d(off)}$			14	25	
Turn-Off Fall Time	t_f			6	10	
Diode forward voltage (note 1)	V_{SD}	$I_S=1.25A, V_{GS}=0V, T_J=25^{\circ}\text{C}$		0.8	1.2	V
Total Gate Charge	Q_g	$V_{GS}=5V, V_{DS}=15V, I_D=2.5A$		3.0	4.5	nC
				6	9	
Gate Source Charge	Q_{gs}	$V_{GS}=10V, V_{DS}=15V, I_D=2.5A$		1.6		
Gate Drain Charge	Q_{gd}			0.6		
Diode forward current(Body Diode)	I_S	$T_C=25^{\circ}\text{C}$			0.62	A

Note:1. Pulse test ; Pulse width $\leq 400\mu s$, Duty cycle $\leq 2\%$

PARAMETER CHARACTERISTIC CURVE

Fig 1: Output Characteristics

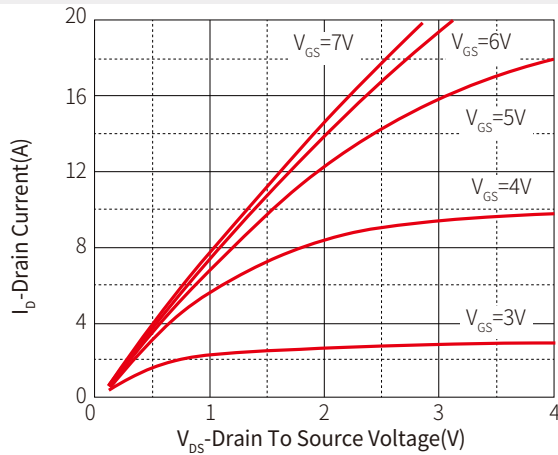


Figure 2: Transfer Characteristics

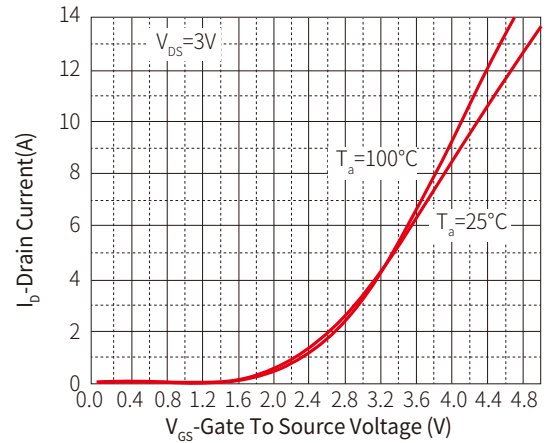


Figure 3: $R_{DS(ON)}$ — I_D

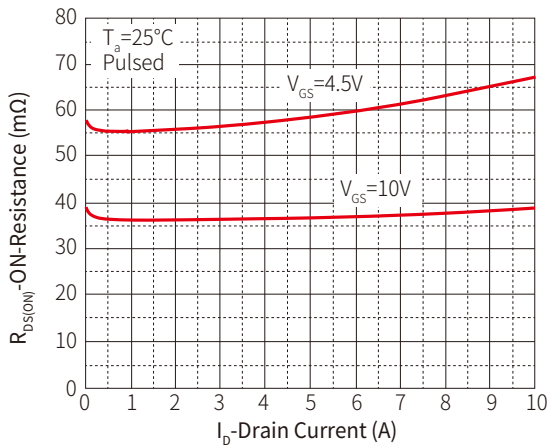


Figure 4: $R_{DS(ON)}$ — V_{GS}

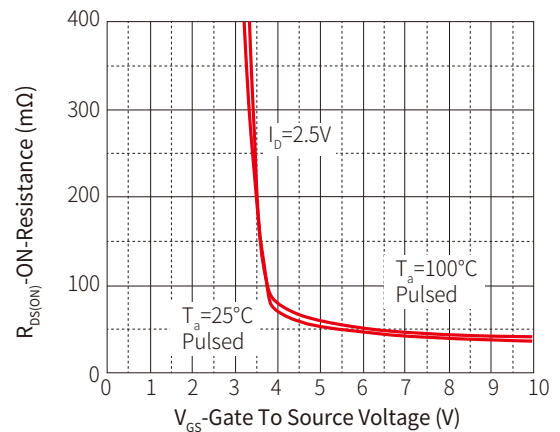


Figure 5: I_S — V_{SD}

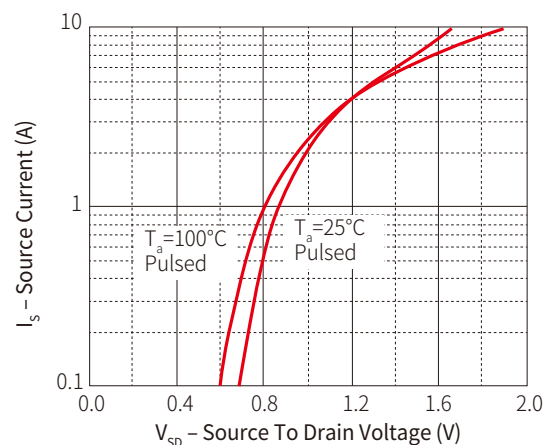
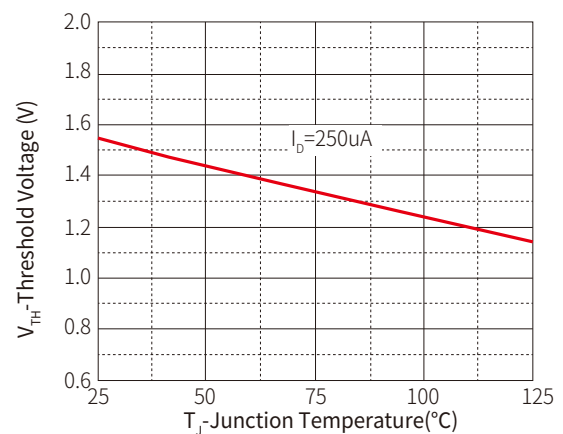
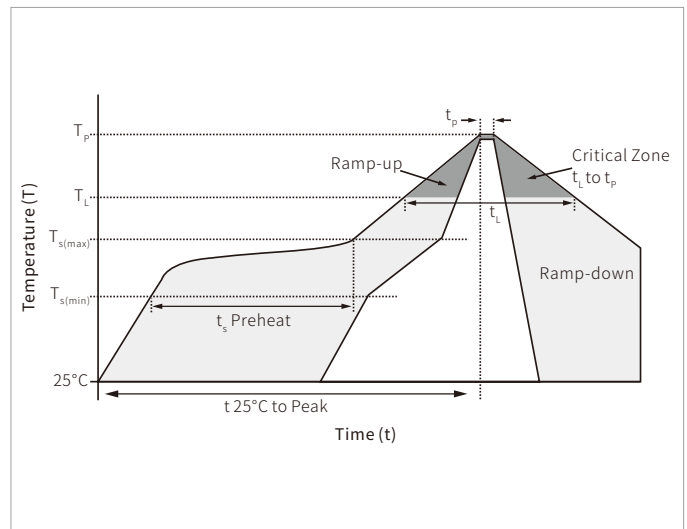


Figure 6: Threshold Voltage

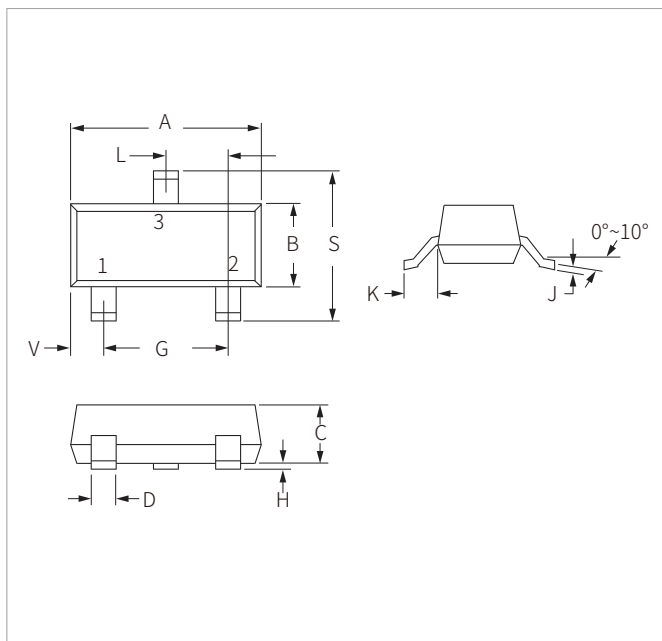


SOLDERING PARAMETERS

Reflow Condition		Lead-free assembly
Pre Heat	Temperature Max ($T_{s(min)}$)	150°C
	Temperature Max ($T_{s(max)}$)	200°C
	Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Time (min to max) (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260°C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes max.
Do not exceed		260°C

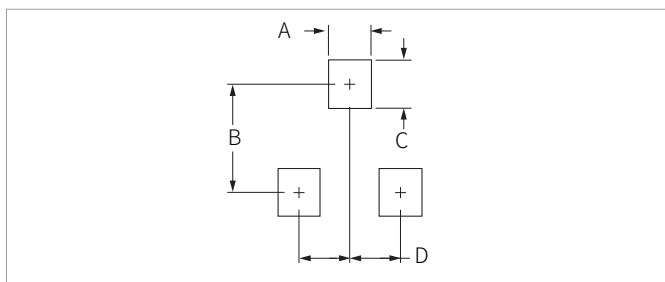


SOT-23 PACKAGE INFORMATION



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.80	3.05	0.110	0.120
B	1.20	1.40	0.047	0.055
C	0.90	1.15	0.035	0.045
D	0.37	0.50	0.015	0.020
G	1.75	2.05	0.069	0.081
H	0.01	0.100	0.001	0.004
J	0.085	0.180	0.003	0.007
K	0.35	0.69	0.014	0.029
L	0.89	1.02	0.035	0.040
S	2.10	2.65	0.083	0.104
V	0.45	0.60	0.018	0.024

RECOMMENDED PAD LAYOUT DIMENSIONS



Ref.	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.71	0.97	0.028	0.038
B	1.88	2.13	0.074	0.084
C	0.71	0.97	0.028	0.038
D	0.81	1.07	0.032	0.042

ORDERING INFORMATION

Part Number	Component Package	QTY/Reel	Reel Size
SNM2306S	SOT-23	3000PCS	7"

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